CMOS Digital Integrated Circuits Silicon Monolithic

# 74HC04D

# 1. Functional Description

Hex Inverter

# 2. General

The 74HC04D is a high speed CMOS INVERTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

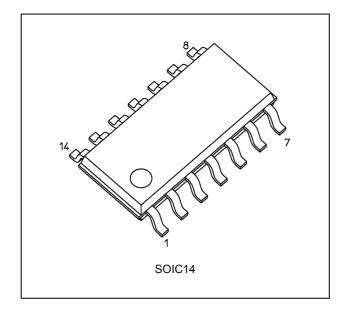
The internal circuit is composed of 3 stages, including buffered output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### 3. Features

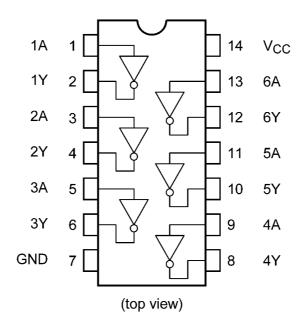
- (1) High speed:  $t_{pd}$  = 6 ns (typ.) at  $V_{CC}$  = 5 V
- (2) Low power dissipation:  $I_{CC} = 1.0 \ \mu A \ (max)$  at  $T_a = 25 \ ^{\circ}C$
- (3) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (4) Wide operating voltage range:  $V_{CC(opr)} = 2.0$  to 6.0 V

## 4. Packaging

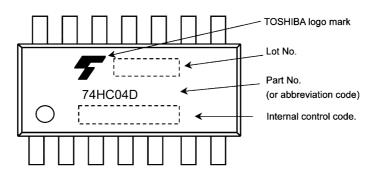


# 5. Pin Assignment

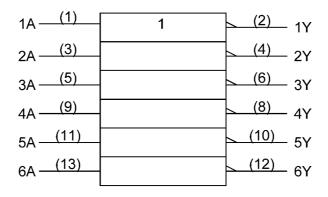
TOSHIBA



# 6. Marking



7. IEC Logic Symbol



# TOSHIBA

#### 8. Truth Table

| А | Y |
|---|---|
| L | Н |
| Н | L |

# 9. Absolute Maximum Ratings (Note)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 7.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Output voltage                  | V <sub>OUT</sub> |          | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current             | I <sub>IK</sub>  |          | ±20                           | mA   |
| Output diode current            | I <sub>OK</sub>  |          | ±20                           | mA   |
| Output current                  | I <sub>OUT</sub> |          | ±25                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           | mA   |
| Power dissipation               | PD               | (Note 1) | 500                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | C°   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $P_D$  derates linearly with -8 mW/°C above 85 °C

## 10. Operating Ranges (Note)

| Characteristics           | Symbol                         | Test Condition | Rating               | Unit |
|---------------------------|--------------------------------|----------------|----------------------|------|
| Supply voltage            | V <sub>CC</sub>                | —              | 2.0 to 6.0           | V    |
| Input voltage             | V <sub>IN</sub>                | —              | 0 to V <sub>CC</sub> | V    |
| Output voltage            | V <sub>OUT</sub>               | _              | 0 to V <sub>CC</sub> | V    |
| Operating temperature     | T <sub>opr</sub>               | —              | -40 to 125           | °C   |
| Input rise and fall times | t <sub>r</sub> ,t <sub>f</sub> | _              | 0 to 50              | μS   |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either  $V_{CC}$  or GND.

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# TOSHIBA

### **11. Electrical Characteristics**

# 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics           | Symbol          | Test Condition                       |                           | V <sub>CC</sub> (V) | Min  | Тур. | Мах  | Unit |
|---------------------------|-----------------|--------------------------------------|---------------------------|---------------------|------|------|------|------|
| High-level input voltage  | VIH             | —                                    |                           | 2.0                 | 1.50 | _    | _    | V    |
|                           |                 |                                      |                           | 4.5                 | 3.15 | _    | _    |      |
|                           |                 |                                      |                           | 6.0                 | 4.20 | _    | —    |      |
| Low-level input voltage   | VIL             | —                                    |                           | 2.0                 |      |      | 0.50 | V    |
|                           |                 |                                      |                           | 4.5                 |      |      | 1.35 |      |
|                           |                 |                                      |                           | 6.0                 |      |      | 1.80 |      |
| High-level output voltage | V <sub>OH</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OH</sub> = -20 μA  | 2.0                 | 1.9  | 2.0  | —    | V    |
|                           |                 |                                      |                           | 4.5                 | 4.4  | 4.5  | —    |      |
|                           |                 |                                      |                           | 6.0                 | 5.9  | 6.0  | —    |      |
|                           |                 |                                      | I <sub>OH</sub> = -4 mA   | 4.5                 | 4.18 | 4.31 | —    |      |
|                           |                 |                                      | I <sub>OH</sub> = -5.2 mA | 6.0                 | 5.68 | 5.80 | —    |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OL</sub> = 20 μA   | 2.0                 |      | 0.0  | 0.1  | V    |
|                           |                 |                                      |                           | 4.5                 |      | 0.0  | 0.1  |      |
|                           |                 |                                      |                           | 6.0                 |      | 0.0  | 0.1  |      |
|                           |                 |                                      | I <sub>OL</sub> = 4 mA    | 4.5                 |      | 0.17 | 0.26 |      |
|                           |                 |                                      | I <sub>OL</sub> = 5.2 mA  | 6.0                 |      | 0.18 | 0.26 |      |
| Input leakage current     | I <sub>IN</sub> | $V_{IN} = V_{CC}$ or GND             |                           | 6.0                 |      |      | ±0.1 | μA   |
| Quiescent supply current  | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND             |                           | 6.0                 |      | _    | 1.0  | μA   |

# 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics           | Symbol          | Test Condition                           |                           | V <sub>CC</sub> (V) | Min  | Max  | Unit |
|---------------------------|-----------------|--|---------------------------|---------------------|------|------|------|
| High-level input voltage  | V <sub>IH</sub> | _  |                           | 2.0                 | 1.50 | _    | V    |
|                           |                 |  |                           | 4.5                 | 3.15 | _    |      |
|                           |                 |  |                           | 6.0                 | 4.20 | _    |      |
| Low-level input voltage   | V <sub>IL</sub> | —  |                           | 2.0                 |      | 0.50 | V    |
|                           |                 |  |                           | 4.5                 |      | 1.35 |      |
|                           |                 |  |                           | 6.0                 |      | 1.80 |      |
| High-level output voltage | V <sub>OH</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$     | I <sub>OH</sub> = -20 μA  | 2.0                 | 1.9  | _    | V    |
|                           |                 |  |                           | 4.5                 | 4.4  | _    |      |
|                           |                 |  |                           | 6.0                 | 5.9  | —    |      |
|                           |                 |  | I <sub>OH</sub> = -4 mA   | 4.5                 | 4.13 | _    |      |
|                           |                 |  | I <sub>OH</sub> = -5.2 mA | 6.0                 | 5.63 | _    |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$     | I <sub>OL</sub> = 20 μA   | 2.0                 |      | 0.1  | V    |
|                           |                 |  |                           | 4.5                 |      | 0.1  |      |
|                           |                 |  |                           | 6.0                 | _    | 0.1  |      |
|                           |                 |  | I <sub>OL</sub> = 4 mA    | 4.5                 | _    | 0.33 |      |
|                           |                 |  | I <sub>OL</sub> = 5.2 mA  | 6.0                 | _    | 0.33 |      |
| Input leakage current     | l <sub>iN</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                           | 6.0                 | _    | ±1.0 | μA   |
| Quiescent supply current  | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND                 |                           | 6.0                 |      | 10.0 | μA   |

# 11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics           | Symbol          | Test Condition                       | I  | V <sub>CC</sub> (V) | Min  | Max  | Unit |
|---------------------------|-----------------|--------------------------------------|--|---------------------|------|------|------|
| High-level input voltage  | V <sub>IH</sub> | —                                    |  | 2.0                 | 1.50 | —    | V    |
|                           |                 |                                      |  | 4.5                 | 3.15 | _    |      |
|                           |                 |                                      |  | 6.0                 | 4.20 | _    |      |
| Low-level input voltage   | V <sub>IL</sub> | _                                    |  | 2.0                 | _    | 0.50 | V    |
|                           |                 |                                      |  | 4.5                 | _    | 1.35 |      |
|                           |                 |                                      |  | 6.0                 | _    | 1.80 |      |
| High-level output voltage | V <sub>OH</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | $V_{\rm IN} = V_{\rm IH} \text{ or } V_{\rm IL}$ $I_{\rm OH} = -20 \ \mu \text{A}$ |                     | 1.9  | _    | V    |
|                           |                 |                                      |  | 4.5                 | 4.4  | _    |      |
|                           |                 |                                      |  | 6.0                 | 5.9  | _    |      |
|                           |                 |                                      | I <sub>OH</sub> = -4 mA  | 4.5                 | 3.7  | _    |      |
|                           |                 |                                      | I <sub>OH</sub> = -5.2 mA  | 6.0                 | 5.2  | _    |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OL</sub> = 20 μA  | 2.0                 | _    | 0.1  | V    |
|                           |                 |                                      |  | 4.5                 | _    | 0.1  |      |
|                           |                 |                                      |  | 6.0                 | _    | 0.1  |      |
|                           |                 |                                      | I <sub>OL</sub> = 4 mA   | 4.5                 | _    | 0.4  |      |
|                           |                 |                                      | I <sub>OL</sub> = 5.2 mA   | 6.0                 | _    | 0.4  |      |
| Input leakage current     | I <sub>IN</sub> | $V_{IN} = V_{CC}$ or GND             |  | 6.0                 | _    | ±1.0 | μA   |
| Quiescent supply current  | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND             |  | 6.0                 | _    | 40.0 | μA   |

#### 11.4. AC Characteristics (Unless otherwise specified, C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, T<sub>a</sub> = 25 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

| Characteristics        | Symbol                             | Test Condition | Min | Тур. | Max | Unit |
|------------------------|------------------------------------|----------------|-----|------|-----|------|
| Output transition time | t <sub>TLH</sub> ,t <sub>THL</sub> | —              | _   | 4    | 8   | ns   |
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | —              |     | 6    | 12  | ns   |

#### 11.5. AC Characteristics (Unless otherwise specified, C<sub>L</sub> = 50 pF, T<sub>a</sub> = 25 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

| Characteristics               | Symbol                             | Note     | V <sub>CC</sub> (V) | Min | Тур. | Max | Unit |
|-------------------------------|------------------------------------|----------|---------------------|-----|------|-----|------|
| Output transition time        | t <sub>TLH</sub> ,t <sub>THL</sub> |          | 2.0                 | _   | 30   | 75  | ns   |
|                               |                                    |          | 4.5                 | _   | 8    | 15  |      |
|                               |                                    |          | 6.0                 | —   | 7    | 13  |      |
| Propagation delay time        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | 2.0                 | —   | 27   | 75  | ns   |
|                               |                                    |          | 4.5                 | _   | 9    | 15  |      |
|                               |                                    |          | 6.0                 | —   | 8    | 13  |      |
| Input capacitance             | C <sub>IN</sub>                    |          | _                   | _   | 3    | _   | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                    | (Note 1) | _                   | _   | 7    | _   | pF   |

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/6 \text{ (per gate)}$ 

# 11.6. AC Characteristics

# (Unless otherwise specified, $C_L = 50 \text{ pF}$ , $T_a = -40 \text{ to } 85 \text{ °C}$ , Input: $t_f = t_f = 6 \text{ ns}$ )

| Characteristics        | Symbol                             | V <sub>CC</sub> (V) | Min | Max | Unit |
|------------------------|------------------------------------|---------------------|-----|-----|------|
| Output transition time | t <sub>TLH</sub> ,t <sub>THL</sub> | 2.0                 | _   | 95  | ns   |
|                        |                                    | 4.5                 | _   | 19  |      |
|                        |                                    | 6.0                 | _   | 16  |      |
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | 2.0                 | —   | 95  | ns   |
|                        |                                    | 4.5                 | _   | 19  |      |
|                        |                                    | 6.0                 | _   | 16  |      |

# 11.7. AC Characteristics

# (Unless otherwise specified, $C_L = 50 \text{ pF}$ , $T_a = -40 \text{ to } 125 \text{ °C}$ , Input: $t_r = t_f = 6 \text{ ns}$ )

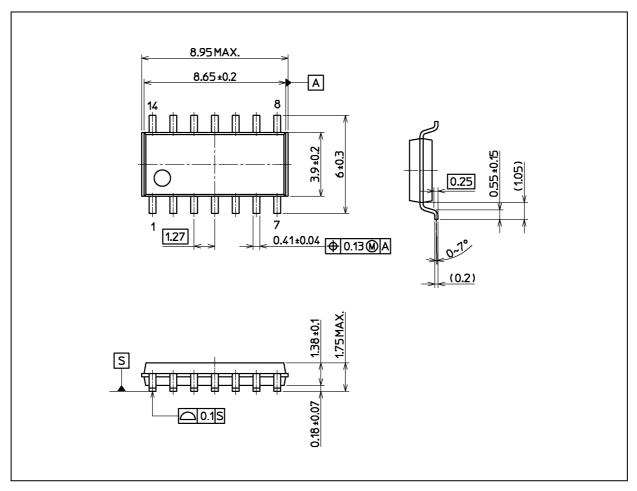
| Characteristics        | Symbol                             | V <sub>CC</sub> (V) | Min | Max | Unit |
|------------------------|------------------------------------|---------------------|-----|-----|------|
| Output transition time | t <sub>TLH</sub> ,t <sub>THL</sub> | 2.0                 | _   | 110 | ns   |
|                        |                                    | 4.5                 | —   | 22  |      |
|                        |                                    | 6.0                 | _   | 19  |      |
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | 2.0                 | _   | 130 | ns   |
|                        |                                    | 4.5                 | —   | 26  |      |
|                        |                                    | 6.0                 | _   | 22  |      |



# Package Dimensions

74HC04D

Unit: mm



Weight: 0.13 g (typ.)

Package Name(s) Nickname: SOIC14

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